

# 25AA128/25LC128

# **128K SPI Bus Serial EEPROM**

#### **Device Selection Table**

Part Number	Vcc Range	Page Size	Temp. Ranges	Packages
25AA128	1.8V-5.5V	64 Byte	I	MF, P, SN, SM, ST
25LC128	2.5V-5.5V	64 Byte	I, E	MF, P, SN, SM, ST

#### Features

- Maximum Clock: 10 MHz
- Low-Power CMOS Technology:
  - Write current (maximum): 5 mA at 5.5V, 10 MHz
  - Read current: 5 mA at 5.5V, 10 MHz
  - Standby current: 5 µA at 5.5V
- 16,384 x 8-Bit Organization
- 64-Byte Page
- Self-Timed Erase and Write Cycles (5 ms maximum)
- Block Write Protection:
  - Protect none, 1/4, 1/2 or all of array
- Built-In Write Protection:
  - Power-on/off data protection circuitry
  - Write enable latch
  - Write-protect pin
- Sequential Read
- High Reliability:
  - Endurance: 1,000,000 erase/write cycles
  - Data retention: >200 years
  - ESD protection: >4000V
- RoHS Compliant
- Temperature Ranges;
  - Industrial (I): -40°C to +85°C
  - Extended (E): -40°C to +125°C
- Automotive AEC-Q100 Qualified

#### Packages

• 8-Lead DFN, 8-Lead PDIP, 8-Lead SOIC, 8-Lead SOIJ and 8-Lead TSSOP

#### **Pin Function Table**

Name	Function			
CS	Chip Select Input			
SO	Serial Data Output			
WP	Write-Protect			
Vss	Ground			
SI	Serial Data Input			
SCK	Serial Clock Input			
HOLD	Hold Input			
Vcc	Supply Voltage			

#### Description

The Microchip Technology Inc. 25AA128/25LC128 (25XX128<sup>(1)</sup>) are 128-Kbit Serial Electrically Erasable PROMs. The memory is accessed via a simple Serial Peripheral Interface (SPI) compatible serial bus. The bus signals required are a clock input (SCK) plus separate data in (SI) and data out (SO) lines. Access to the device is controlled through a Chip Select ( $\overline{\text{CS}}$ ) input.

Communication to the device can be paused via the hold pin (HOLD). While the device is paused, transitions on its inputs will be ignored, with the exception of Chip Select, allowing the host to service higher priority interrupts.

Note 1: 25XX128 is used in this document as a generic part number for the 25AA128/25LC128 devices.

DFN	PDIP/SO	C/SOIJ	TSSOP	Rot	ated TSSOP
CS 1•	8 VCC CS 1	8 VCC CS	1 8	Vcc         HOLD         1           HOLD         Vcc         2           SCK         CS         3           SI         SO         4	8 SCK
SO 2	7 HOLD SO 2	7 HOLD SO 6	2 7		7 SI
WP 3	6 SCK WP 3	6 SCK WP 5	3 6		6 Vss
Vss 4	5 SI Vss 4	5 SI VSS 5	4 5		5 WP

### 1.0 ELECTRICAL CHARACTERISTICS

#### Absolute Maximum Ratings (†)

Vcc	6.5V
All inputs and outputs w.r.t. Vss	-0.6V to Vcc +1.0V
Storage temperature	65°C to +150°C
Ambient temperature under bias	40°C to +125°C
ESD protection on all pins	4 kV

**† NOTICE:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for an extended period of time may affect device reliability.

TABLE 1-1:	DC CHARACTERISTICS	

DC CHARACTERISTICS			Industrial (I): TA = -40°C to +85°C Vcc = 1.8V to 5.5V Extended (E): TA = -40°C to +125°C Vcc = 2.5V to 5.5V			
Param. No.	Symbol	Characteristic	Minimum	Maximum	Units	Conditions
D1	Vін	High-Level Input Voltage	0.7 Vcc	Vcc+1	V	
D2	VIL1	Low-Level Input Voltage	-0.3	0.3 Vcc	V	$Vcc \ge 2.7V$
D3	VIL2	Low-Level input voltage	-0.3	0.2 Vcc	V	Vcc < 2.7V
D4	Vol	Low-Level Output Voltage	—	0.4	V	IOL = 2.1 mA
D5	Vol		—	0.2	V	IoL = 1.0 mA, Vcc < 2.5V
D6	Vон	High-Level Output Voltage	Vcc -0.5	—	V	Іон = -400 μА
D7	Iц	Input Leakage Current	—	±1	μA	CS = Vcc, VIN = Vss or Vcc
D8	Ilo	Output Leakage Current	—	±1	μA	CS = Vcc, Vout = Vss or Vcc
D9	CINT	Internal Capacitance (all inputs and outputs)	—	7	pF	TA = +25°C, CLK = 1.0 MHz, Vcc = 5.0V ( <b>Note 1</b> )
D10	loo Dood		—	5	mA	Vcc = 5.5V, FcLk = 10.0 MHz, SO = Open
	ICC Read	Operating Current	—	2.5	mA	Vcc = 2.5V, FcLk = 5.0 MHz SO = Open
D11	Loc Mrite	Operating Current	_	5	mA	Vcc = 5.5V
	ICC Write	Operating Current		3	mA	Vcc = 2.5V
D12		Standby Current	—	5	μA	CS = Vcc = 5.5V, Inputs tied to Vcc or Vss, +125°C
צוט	D12 Iccs	Standby Current	—	1	μA	CS = Vcc = 5.5V, Inputs tied to Vcc or Vss, +85°C

Note 1:	This parameter is	periodically sampled and not 100% tested.
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AC CHARACTERISTICS						C Vcc = 1.8V to 5.5V °C Vcc = 2.5V to 5.5V
Param. No.	Symbol	Characteristic	Minimum	Maximum	Units	Conditions
			_	10	MHz	$4.5V \le Vcc \le 5.5V$
1	FCLK	Clock Frequency	_	5	MHz	$2.5V \leq Vcc < 4.5V$
			_	3	MHz	$1.8V \leq Vcc < 2.5V$
			50	—	ns	$4.5V \le Vcc \le 5.5V$
2	Tcss	CS Setup Time	100	—	ns	$2.5V \leq Vcc < 4.5V$
			150	—	ns	$1.8V \leq Vcc < 2.5V$
			100	—	ns	$4.5V \leq Vcc \leq 5.5V$
3	Тсѕн	CS Hold Time	200	—	ns	$2.5V \leq Vcc < 4.5V$
			250	_	ns	$1.8V \leq Vcc < 2.5V$
4	TCSD	CS Disable Time	50	_	ns	
			10	_	ns	$4.5V \le Vcc \le 5.5V$
5	Tsu	Data Setup Time	20	_	ns	$2.5V \leq Vcc < 4.5V$
			30	—	ns	$1.8V \leq Vcc < 2.5V$
		Data Hold Time	20		ns	$4.5V \leq Vcc \leq 5.5V$
6	THD		40		ns	$2.5V \leq Vcc < 4.5V$
			50	—	ns	$1.8V \leq Vcc < 2.5V$
7	TR	CLK Rise Time		100	ns	Note 1
8	TF	CLK Fall Time		100	ns	Note 1
			50		ns	$4.5V \leq Vcc \leq 5.5V$
9	Тні	Clock High Time	100	_	ns	$2.5V \leq Vcc < 4.5V$
			150	—	ns	$1.8V \leq Vcc < 2.5V$
		Clock Low Time	50	_	ns	$4.5V \leq Vcc \leq 5.5V$
10	Tlo		100	_	ns	$2.5V \leq Vcc < 4.5V$
			150	—	ns	$1.8V \leq Vcc < 2.5V$
11	TCLD	Clock Delay Time	50		ns	
12	TCLE	Clock Enable Time	50	_	ns	
				50	ns	$4.5V \leq Vcc \leq 5.5V$
13	Τv	Output Valid from Clock Low		100	ns	$2.5V \leq Vcc < 4.5V$
				160	ns	$1.8V \leq Vcc < 2.5V$
14	Тно	Output Hold Time	0	_	ns	Note 1
			_	40	ns	$4.5V \le Vcc \le 5.5V$ (Note 1)
15	TDIS	Output Disable Time	_	80	ns	$2.5V \le Vcc \le 4.5V$ (Note 1)
			_	160	ns	$1.8V \le Vcc \le 2.5V$ (Note 1)
			20	—	ns	$4.5V \le Vcc \le 5.5V$
16	Tнs	HOLD Setup Time	40	—	ns	$2.5V \leq Vcc < 4.5V$
			80	_	ns	1.8V ≤ Vcc < 2.5V

#### TABLE 1-2: AC CHARACTERISTICS

**Note 1:** This parameter is periodically sampled and not 100% tested.

2: This parameter is not tested but ensured by characterization.

AC CHARACTERISTICS			Industrial (I): TA = -40°C to +85°C Vcc = 1.8V to 5.5V Extended (E): TA = -40°C to +125°C Vcc = 2.5V to 5.5V				
Param. No.	Symbol	Characteristic	Minimum	Maximum	Units	Conditions	
			20	_	ns	$4.5V \le Vcc \le 5.5V$	
17	Тнн	HOLD Hold Time	40	_	ns	$2.5V \leq Vcc < 4.5V$	
			80	_	ns	$1.8V \leq Vcc < 2.5V$	
	8 Тнz	HOLD Low to Output High-Z	_	30	ns	$4.5V \le Vcc \le 5.5V$ (Note 1)	
18			_	60	ns	$2.5V \leq Vcc < 4.5V$ (Note 1)	
	i ligit Z	_	160	ns	$1.8V \leq Vcc < 2.5V$ (Note 1)		
			_	30	ns	$4.5V \le Vcc \le 5.5V$	
19	9 Тнv	HOLD High to Output Valid	_	60	ns	$2.5V \leq Vcc < 4.5V$	
	valiu	_	160	ns	$1.8V \leq Vcc < 2.5V$		
20	Twc	Internal Write Cycle Time	_	5	ms		
21		Endurance	1M		E/W Cycles	+25°C, Vcc = 5.5V (Note 2)	

#### TABLE 1-2: AC CHARACTERISTICS (CONTINUED)

**Note 1:** This parameter is periodically sampled and not 100% tested.

2: This parameter is not tested but ensured by characterization.

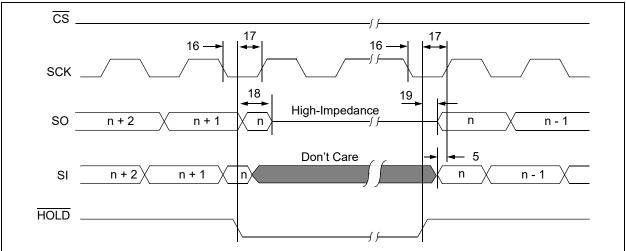
#### TABLE 1-3: AC TEST CONDITIONS

AC Waveform:					
VLO = 0.2V	—				
VHI = VCC - 0.2V	Note 1				
VHI = 4.0V	Note 2				
CL = 50 pF	—				
Timing Measurement Reference Level					
Input	0.5 Vcc				
Output	0.5 Vcc				

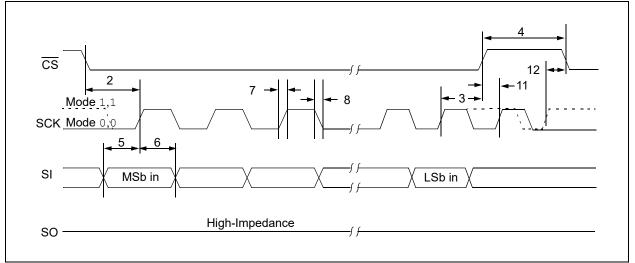
Note 1: For VCC  $\leq 4.0V$ 

**2:** For Vcc > 4.0V

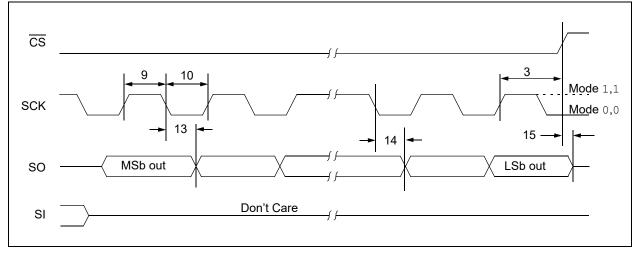
#### FIGURE 1-1: HOLD TIMING



#### FIGURE 1-2: SERIAL INPUT TIMING



#### FIGURE 1-3: SERIAL OUTPUT TIMING



### 2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

Name	DFN <sup>(1)</sup>	PDIP	SOIC	SOIJ	TSSOP	Rotated TSSOP	Function
CS	1	1	1	1	1	3	Chip Select Input
SO	2	2	2	2	2	4	Serial Data Output
WP	3	3	3	3	3	5	Write-Protect Pin
Vss	4	4	4	4	4	6	Ground
SI	5	5	5	5	5	7	Serial Data Input
SCK	6	6	6	6	6	8	Serial Clock Input
HOLD	7	7	7	7	7	1	Hold Input
Vcc	8	8	8	8	8	2	Supply Voltage

#### TABLE 2-1: PIN FUNCTION TABLE

**Note 1:** The exposed pad on the DFN package can be connected to Vss or left floating.

### 2.1 Chip Select (CS)

A low level on this pin selects the device. A high level deselects the device and forces it into Standby mode. However, a programming cycle which is already initiated or in progress will be completed, regardless of  $\overline{CS}$  input signal. If  $\overline{CS}$  is brought high during a program cycle, the device will go into Standby mode as soon as programming cycle is complete. When the device is deselected, SO goes to high-impedance state, allowing multiple parts to share the same SPI bus. A low-to-high transition on  $\overline{CS}$  after a valid write sequence initiates an internal write cycle. After power-up, a low level on  $\overline{CS}$  is required prior to any sequence being initiated.

#### 2.2 Serial Output (SO)

The SO pin is used to transfer data out of the 25XX128. During a read cycle, data are shifted out on this pin after the falling edge of the serial clock.

### 2.3 Write-Protect (WP)

This pin is used in conjunction with the WPEN bit in the STATUS register to prohibit writes to the nonvolatile bits in the STATUS register. When WP is low and WPEN is high, writing to the nonvolatile bits in the STATUS register is disabled. All other operations function normally. When  $\overline{WP}$  is high, all functions, including writes to the nonvolatile bits in the STATUS register, operate normally. If the WPEN bit is set, WP low during a STATUS register write sequence will disable writing to the STATUS register. If an internal write cycle has already begun, WP going low will have no effect on the write. The WP pin function is blocked when the WPEN bit in the STATUS register is low. This allows the user to install the 25XX128 in a system with WP pin grounded and still be able to write to the STATUS register. The WP pin functions will be enabled when the WPEN bit is set high.

### 2.4 Serial Input (SI)

The SI pin is used to transfer data into the device. It receives instructions, addresses and data. Data are latched on the rising edge of the serial clock.

#### 2.5 Serial Clock (SCK)

The SCK is used to synchronize the communication between a master and the 25XX128. Instructions, addresses or data present on the SI pin are latched on the rising edge of the clock input, while data on the SO pin is updated after the falling edge of the clock input.

### 2.6 Hold (HOLD)

The HOLD pin is used to suspend transmission to the 25XX128 while in the middle of a serial sequence without having to retransmit the entire sequence again. It must be held high any time this function is not being used. Once the device is selected and a serial sequence is underway, the HOLD pin may be pulled low to pause further serial communication without resetting the serial sequence.

The HOLD pin must be brought low while SCK is low, otherwise the HOLD function will not be invoked until the next SCK high-to-low transition. The 25XX128 must remain selected during this sequence. The SI and SCK levels are "don't cares" during the time the device is paused and any transitions on these pins will be ignored. To resume serial communication, HOLD must be brought high while the SCK pin is low, otherwise serial communication will not be resumed until the next SCK high-to-low transition.

The SO line will tri-state immediately upon a high-to-low transition of the HOLD pin, and will begin outputting again immediately upon a subsequent low-to-high transition of the HOLD pin, independent of the state of SCK.

#### 3.0 FUNCTIONAL DESCRIPTION

#### 3.1 **Principles of Operation**

The 25XX128 is a 16,384-byte Serial EEPROM designed to interface directly with the Serial Peripheral Interface (SPI) port of many of today's popular microcontroller families, including Microchip's PIC® microcontrollers. It may also interface with microcontrollers that do not have a built-in SPI port by using discrete I/O lines programmed properly in firmware to match the SPI protocol.

The 25XX128 contains an 8-bit instruction register. The device is accessed via the SI pin, with data being clocked in on the rising edge of SCK. The  $\overline{\text{CS}}$  pin must be low and the HOLD pin must be high for the entire operation.

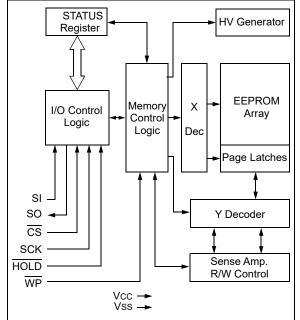
Table 3-1 contains a list of the possible instruction bytes and format for device operation. All instructions, addresses and data are transferred MSb first, LSb last.

Data (SI) are sampled on the first rising edge of SCK after  $\overline{CS}$  goes low. If the clock line is shared with other peripheral devices on the SPI bus, the user can assert the HOLD input and place the 25XX128 in 'HOLD' mode. After releasing the HOLD pin, operation will resume from the point when the HOLD was asserted.

**INSTRUCTION SET** 

**TABLE 3-1:** 

#### **BLOCK DIAGRAM**



Instruction Name	Instruction Format	Description
READ	0000 0011	Read data from memory array beginning at selected address
WRITE	0000 0010	Write data to memory array beginning at selected address
WRDI	0000 0100	Reset the write enable latch (disable write operations)
WREN	0000 0110	Set the write enable latch (enable write operations)
RDSR	0000 0101	Read STATUS register
WRSR	0000 0001	Write STATUS register

#### 3.2 Read Sequence

The device is selected by pulling  $\overline{\text{CS}}$  low. The 8-bit READ instruction is transmitted to the 25XX128 followed by the 16-bit address, with two MSBs of the address being "don't care" bits. After the correct READ instruction and address are sent, the data stored in the memory at the selected address are shifted out on the SO pin. The data stored in the memory at the next address can be read sequentially by continuing to provide clock pulses. The internal Address Pointer is automatically incremented to the next higher address after each byte of data is shifted out. When the highest address is reached (3FFFh), the address counter rolls over to address 0000h, allowing the read cycle to be continued indefinitely. The read operation is terminated by raising the  $\overline{\text{CS}}$  pin (Figure 3-1).

#### 3.3 Write Sequence

Prior to any attempt to write data to the 25XX128, the write enable latch must be set by issuing the WREN instruction (Figure 3-4). This is done by setting  $\overline{CS}$  low and then clocking out the proper instruction into the 25XX128. After all eight bits of the instruction are transmitted, the  $\overline{CS}$  must be brought high to set the write enable latch. If the write operation is initiated immediately after the WREN instruction without  $\overline{CS}$  being brought high, the data will not be written to the array because the write enable latch will not have been properly set.

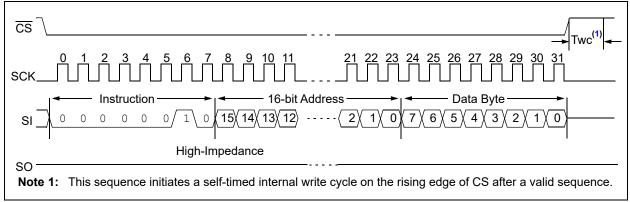
Once the write enable latch is set, the user may proceed by setting the  $\overline{CS}$  low, issuing a WRITE instruction, followed by the 16-bit address, with two MSBs of the address being "don't care" bits, and then the data to be written. Up to 64 bytes of data can be sent to the device before a write cycle is necessary. The only restriction is that all of the bytes must reside in the same page.

Note: Page write operations are limited to writing bytes within a single physical page, regardless of the number of bytes actually being written. Physical page boundaries start at addresses that are integer multiples of the page buffer size (or 'page size') and end at addresses that are integer multiples of page size - 1. If a Page Write command attempts to write across a physical page boundary, the result is that the data wrap around to the beginning of the current page (overwriting data previously stored there), instead of being written to the next page as might be expected. It is therefore necessary for the application software to prevent page write operations that would attempt to cross a page boundary.

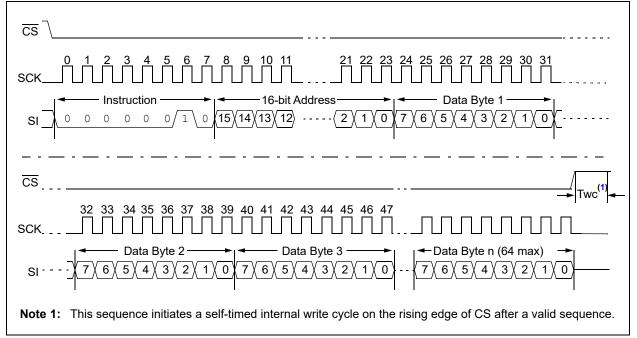
For the data to be actually written to the array, the  $\overline{CS}$  must be brought high after the Least Significant bit (D0) of the  $n^{th}$  data byte has been clocked in. If  $\overline{CS}$  is brought high at any other time, the write operation will not be completed. Refer to Figure 3-2 and Figure 3-3 for more detailed illustrations on the byte write sequence and the page write sequence, respectively. While the write is in progress, the STATUS register may be read to check the status of the Write-In-Process (WIP) bit (Figure 3-6). A read attempt of a memory array location will not be possible during a write cycle. When the write cycle is completed, the write enable latch is reset.

#### FIGURE 3-1: **READ SEQUENCE** CS 11 21 22 23 9 10 SCK Instruction 16-bit Address 0 0 0 0/ 0 0 0 1 1 15 \ 14 13 12 2 1 SI Data Out High-Impedance 4 \ 3 \ 5 X 2 7 6 X 1 0 SO





#### FIGURE 3-3: PAGE WRITE SEQUENCE

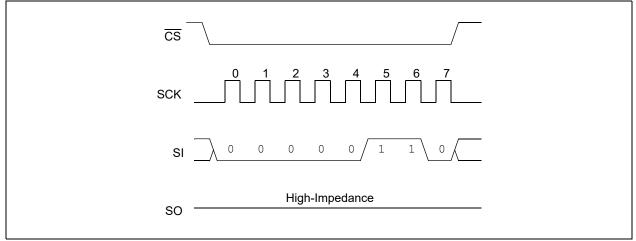


#### 3.4 Write Enable (WREN) and Write Disable (WRDI)

The 25XX128 contains a write enable latch. See Table 3-4 for the write-protect functionality matrix. This latch must be set before any write operation will be completed internally. The WREN instruction will set the latch, and the WRDI will reset the latch.

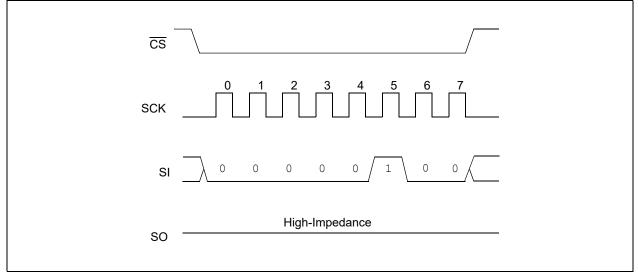
The following is a list of conditions under which the write enable latch will be reset:

- Power-up
- WRDI instruction successfully executed
- WRSR instruction successfully executed
- WRITE instruction successfully executed



#### FIGURE 3-4: WRITE ENABLE SEQUENCE (WREN)





#### 3.5 **Read STATUS Register Instruction** (RDSR)

The Read STATUS Register instruction (RDSR) provides access to the STATUS register. The STATUS register may be read at any time, even during a write cycle. The STATUS register is formatted as follows:

7	6	5	4	3	2	1	0	
W/R	-	-	Ι	W/R	W/R	R	R	
WPEN	Х	Х	Х	BP1	BP0	WEL	WIP	
Noto	<b>Note:</b> $M/P = writeble/readable P = read only$							

**TABLE 3-2:** STATUS REGISTER

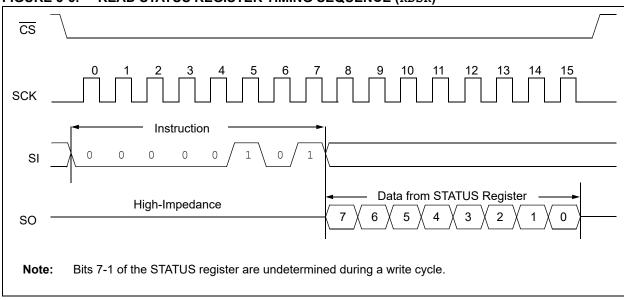
Note: W/R = writable/readable. R = read-only.

The Write-In-Process (WIP) bit indicates whether the 25XX128 is busy with a write operation. When set to a '1', a write is in progress, when set to a '0', no write is in progress. This bit is read-only.

The Write Enable Latch (WEL) bit indicates the status of the write enable latch and is read-only. When set to a '1', the latch allows writes to the array, when set to a '0', the latch prohibits writes to the array. The state of this bit can always be updated via the WREN or WRDI commands regardless of the state of write protection on the STATUS register. These commands are shown in Figure 3-4 and Figure 3-5.

The Block Protection (BP0 and BP1) bits indicate which blocks are currently write-protected. These bits are set by the user issuing the WRSR instruction. These bits are nonvolatile, and are shown in Table 3-3.

See Figure 3-6 for the RDSR timing sequence.





#### 3.6 Write STATUS Register (WRSR)

The Write STATUS Register (WRSR) instruction allows the user to write to the nonvolatile bits in the STATUS register as shown in Table 3-2. The user is able to select one of four levels of protection for the array by writing to the appropriate bits in the STATUS register. The array is divided up into four segments. The user has the ability to write-protect none, one, two, or all four of the segments of the array. The partitioning is controlled as shown in Table 3-3.

The Write-Protect Enable (WPEN) bit is a nonvolatile bit that is available as an enable bit for the WP pin. The Write-Protect (WP) pin and the Write-Protect Enable (WPEN) bit in the STATUS register control the programmable hardware write-protect <u>feature</u>. Hardware write protection is enabled when WP pin is low and the WPEN bit is high. Hardware write protection is disabled when either the WP pin is high or the WPEN bit is low. When the chip is hardware write-protected, only writes to nonvolatile bits in the STATUS register are disabled. See Table 3-4 for a matrix of functionality on the WPEN bit.

BP1	BP0	Array Addresses Write-Protected
0	0	none
0	1	upper 1/4 (3000h-3FFFh)
1	0	upper 1/2 (2000h-3FFFh)
1	1	all (0000h-3FFFh)

#### TABLE 3-3: ARRAY PROTECTION

See Figure 3-7 for the WRSR timing sequence.

#### FIGURE 3-7: WRITE STATUS REGISTER TIMING SEQUENCE (WRSR)

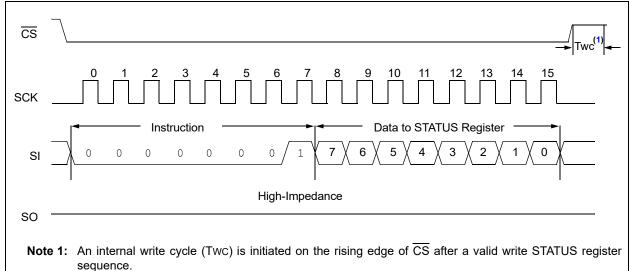


TABLE 3-4:	WRITE-PROTECT FUNCTIONALITY MATRIX	

WEL (SR bit 1)	WPEN (SR bit 7)	WP (pin 3)	Protected Blocks   Ur		STATUS Register						
0	х	х	Protected	Protected	Protected						
1	0	х	Protected	Writable	Writable						
1	1	0 (low)	Protected	Writable	Protected						
1	1	1 (high)	Protected	Writable	Writable						

**Note:** x = don't care

### 4.0 DATA PROTECTION

The following protection has been implemented to prevent inadvertent writes to the array:

- The write enable latch is reset on power-up
- A write enable instruction must be issued to set the write enable latch
- After a byte write, page write or STATUS register write, the write enable latch is reset
- CS must be set high after the proper number of clock cycles to start an internal write cycle
- Access to the array during an internal write cycle is ignored and programming is continued

### 5.0 POWER-ON STATE

The 25XX128 powers on in the following state:

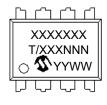
- The device is in low-power Standby mode  $(\overline{CS} = 1)$
- The write enable latch is reset
- SO is in high-impedance state
- A high-to-low-level transition on CS is required to enter active state

#### 6.0 PACKAGING INFORMATION

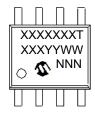
#### 6.1 Package Marking Information



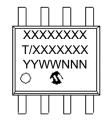
8-Lead PDIP (300 mil)



8-Lead SOIC (3.90 mm)



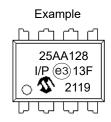
8-Lead SOIJ (5.28 mm)

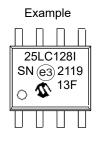


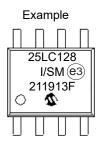
8-Lead TSSOP



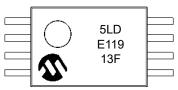












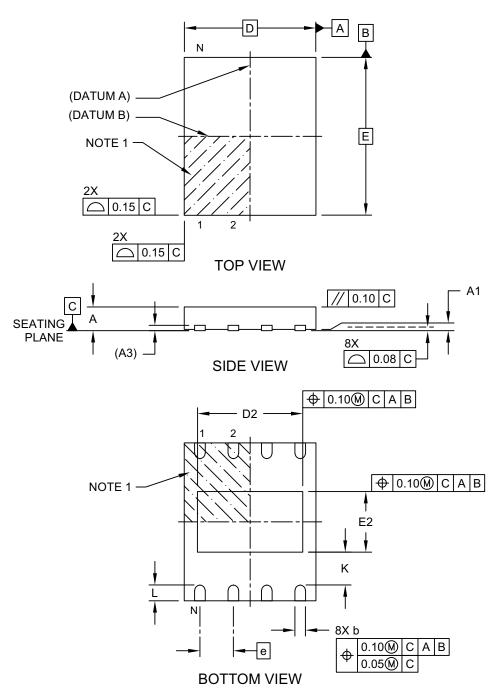
Part	1 <sup>st</sup> Line Marking Codes					
No.	DFN	PDIP	SOIC	SOIJ	TSSOP	Rotated TSSOP
25AA128	25AA128	25AA128	25AA128T	25AA128	5AD	5ADX
25LC128	25LC128	25LC128	25LC128T	25AA128	5LD	5LDX

**Note 1:** T = Temperature grade (I, E)

Legend	I: XXX T Y YY WW	Part number or part number code Temperature (I, E) Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01')
	NNN @3	Alphanumeric traceability code (2 characters for small packages) $JEDEC^{\circledast}$ designator for Matte Tin (Sn)
Note:	_ /	small packages with no room for the JEDEC <sup>®</sup> designator narking will only appear on the outer carton or reel label.
Note:	be carrie	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.

#### 8-Lead Plastic Dual Flat, No Lead Package (MF) - 6x5 mm Body [DFN-S] Saw Singulated

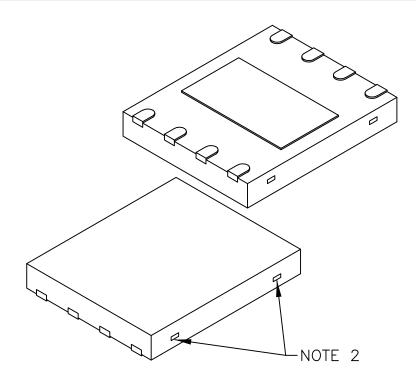
**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-122 Rev C Sheet 1 of 2

#### 8-Lead Plastic Dual Flat, No Lead Package (MF) - 6x5 mm Body [DFN-S] Saw Singulated

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	N	MILLIMETERS		
Dimension Limit		MIN	NOM	MAX	
Number of Terminals	N		8		
Pitch	е		1.27 BSC		
Overall Height	Α	0.80	0.85	1.00	
Standoff	A1	0.00	0.02	0.05	
Terminal Thickness	A3		0.20 REF		
Overall Length	D	5.00 BSC			
Exposed Pad Length	D2	3.90	4.00	4.10	
Overall Width	E		6.00 BSC		
Exposed Pad Width	E2	2.20	2.30	2.40	
Terminal Width	b	0.30	0.40	0.50	
Terminal Length	L	0.50	0.60	0.75	
Terminal-to-Exposed-Pad	К	0.20	-	-	

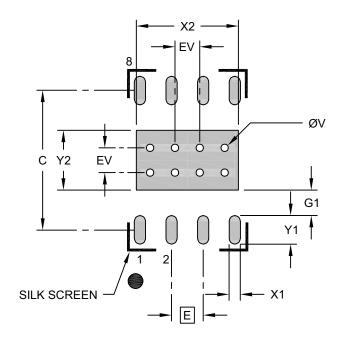
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one ore more exposed tie bars at ends.
- 3. Package is saw singulated
- 4. Dimensioning and tolerancing per ASME Y14.5M
  - BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-122 Rev C Sheet 2 of 2

#### 8-Lead Plastic Dual Flat, No Lead Package (MF) - 6x5 mm Body [DFN-S] Saw Singulated

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



#### **RECOMMENDED LAND PATTERN**

	Ν	/ILLIMETER	S	
Dimensior	Dimension Limits		NOM	MAX
Contact Pitch	E	1.27 BSC		
Optional Center Pad Width	X2			2.40
Optional Center Pad Length	Y2			4.10
Contact Pad Spacing	С		5.60	
Contact Pad Width (X20)	X1			0.45
Contact Pad Length (X20)	Y1			1.15
Contact Pad to Center Pad (X20)	G1	0.20		
Thermal Via Diameter	V		0.30	
Thermal Via Pitch	EV		1.00	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

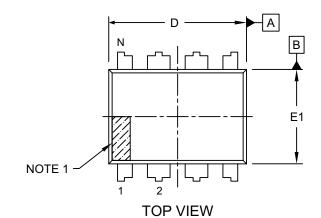
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

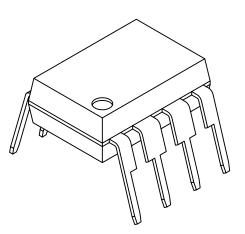
2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

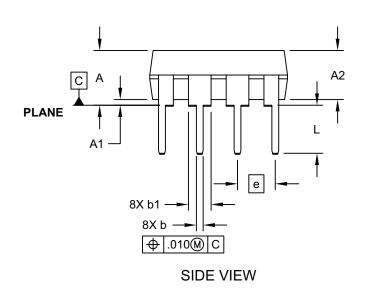
Microchip Technology Drawing C04-2122 Rev C

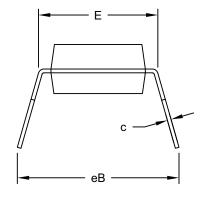
#### 8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging







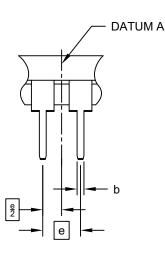


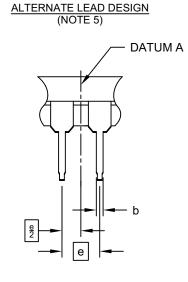
**END VIEW** 

Microchip Technology Drawing No. C04-018-P Rev E Sheet 1 of 2

#### 8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





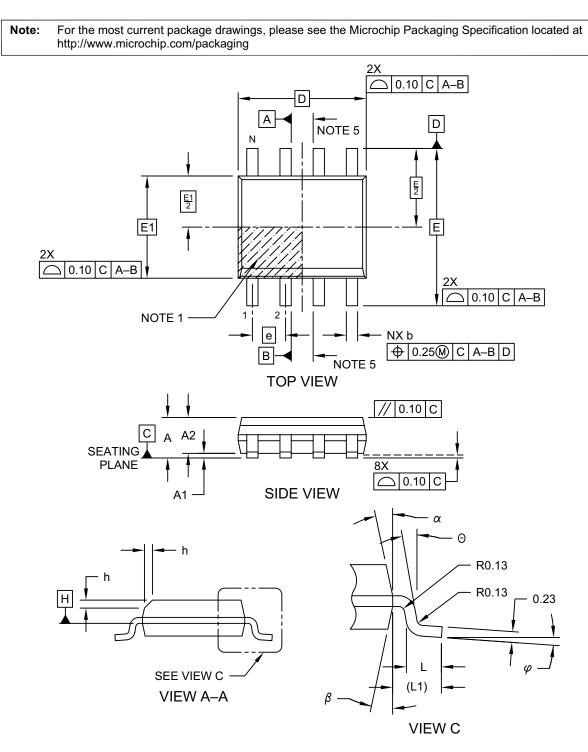
Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins	Ν		8	
Pitch	е		.100 BSC	
Top to Seating Plane	Α	-	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	-	-
Shoulder to Shoulder Width	Е	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	С	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eВ	-	-	.430

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M
- BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 5. Lead design above seating plane may vary, based on assembly vendor.

Microchip Technology Drawing No. C04-018-P Rev E Sheet 2 of 2

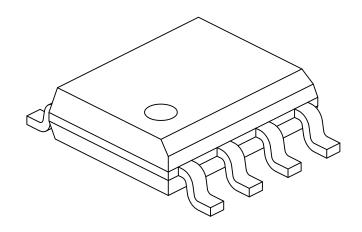
#### 8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]



Microchip Technology Drawing No. C04-057-SN Rev F Sheet 1 of 2

#### 8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		1.27 BSC		
Overall Height	A	-	-	1.75	
Molded Package Thickness	A2	1.25	-	-	
Standoff §	A1	0.10	-	0.25	
Overall Width	E	6.00 BSC			
Molded Package Width	E1	3.90 BSC			
Overall Length	D	4.90 BSC			
Chamfer (Optional)	h	0.25	-	0.50	
Foot Length	L	0.40	-	1.27	
Footprint	L1	1.04 REF			
Foot Angle	φ	0°	-	8°	
Lead Thickness	С	0.17	-	0.25	
Lead Width	b	0.31	-	0.51	
Mold Draft Angle Top	α	5°	-	15°	
Mold Draft Angle Bottom	β	5°	-	15°	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.

4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

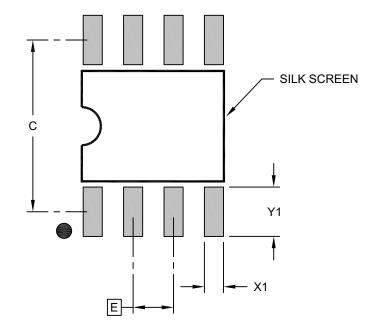
REF: Reference Dimension, usually without tolerance, for information purposes only.

5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-057-SN Rev F Sheet 2 of 2

#### 8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



#### RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Contact Pitch	Е		1.27 BSC	
Contact Pad Spacing	С		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

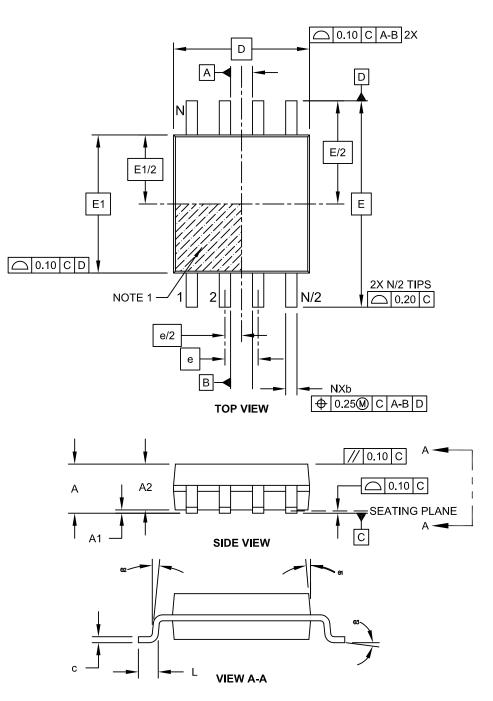
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2057-SN Rev F

#### 8-Lead Plastic Small Outline (SM) - Medium, 5.28 mm Body [SOIJ]

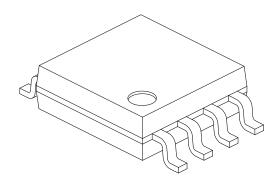
**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-056C Sheet 1 of 2

#### 8-Lead Plastic Small Outline (SM) - Medium, 5.28 mm Body [SOIJ]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		MILLIMETER	S	
Dimensio	on Limits	MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		1.27 BSC	_	
Overall Height	A	1 <u>.</u> 77	-	2.03	
Standoff §	A1	0.05		0.25	
Molded Package Thickness	A2	1.75	-	1.98	
Overall Width	E	7.94 BSC			
Molded Package Width	E1		5.25 BSC		
Overall Length	D		5.26 BSC		
Foot Length	L	0.51	-	0.76	
Lead Thickness	С	0.15	-	0.25	
Lead Width	b	0.36	-	0.51	
Mold Draft Angle	Θ1	-	-	15°	
Lead Angle	Θ2	0°	-	8°	
Foot Angle	Θ3	0°	-	8°	

Notes:

1. SOIJ, JEITA/EIAJ Standard, Formerly called SOIC

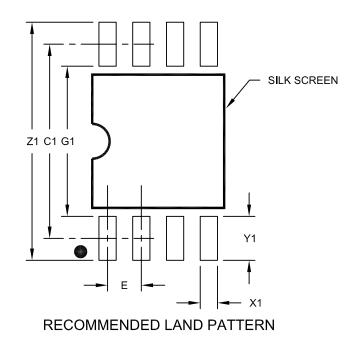
2. § Significant Characteristic

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.25mm per side.

Microchip Technology Drawing No. C04-056C Sheet 2 of 2

8-Lead Plastic Small Outline (SM) - Medium, 5.28 mm Body [SOIJ]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			MILLIMETERS			
Dimension Limits		MIN	NOM	MAX			
Contact Pitch E		1.27 BSC					
Overall Width	Z1			9.00			
Contact Pad Spacing	C1		7.30				
Contact Pad Width (X8)	X1			0.65			
Contact Pad Length (X8)	Y1			1.70			
Distance Between Pads	G1	5.60					
Distance Between Pads	G	0.62					

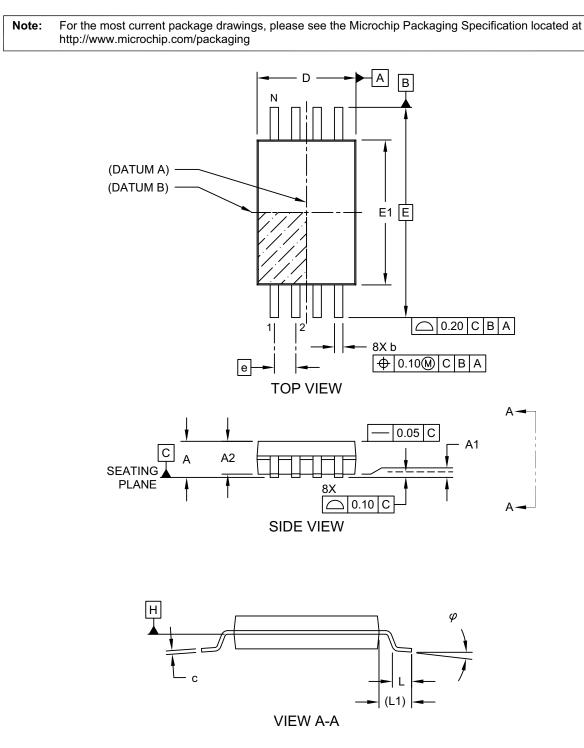
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2056C

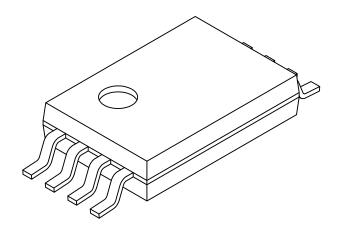
### 8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]



Microchip Technology Drawing C04-086 Rev C Sheet 1 of 2

#### 8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Number of Pins	N	8		
Pitch	е	0.65 BSC		
Overall Height	Α	1.		
Molded Package Thickness	A2	0.80	1.00	1.05
Standoff	A1	0.05	-	-
Overall Width	E		6.40 BSC	
Molded Package Width	E1	4.30	4.40	4.50
Overall Length	D	2.90	3.00	3.10
Foot Length	L	0.45	0.60	0.75
Footprint	L1	1.00 REF		
Lead Thickness	С	0.09	-	0.25
Foot Angle	φ	0°	4°	8°
Lead Width	b	0.19	-	0.30

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.20mm per side.

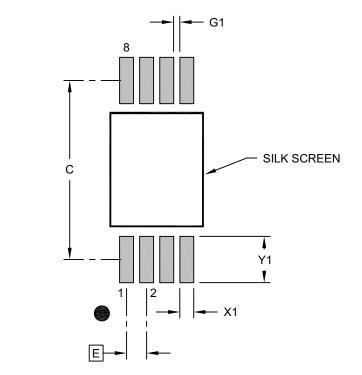
3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-086 Rev C Sheet 2 of 2

#### 8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



#### RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	0.65 BSC		
Contact Pad Spacing	С		5.80	
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.50
Contact Pad to Center Pad (X6)	G1	0.20		

#### Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-2086 Rev B

### APPENDIX A: REVISION HISTORY

#### Revision G (08/2021)

Added automotive product ID section; Reformatted some sections for better readability; Updated DFN-S, SOIC and TSSOP package drawings.

#### **Revision F (08/2019)**

Updated content throughout for clarification; Update 8L PDIP Package Drawing.

#### Revision E (07/2011)

Added SOIJ (SM) package.

#### Revision D (06/2009)

Added X-Rotated TSSOP to package types; Revised Table 1-2, Param. 21; Revised Table 3-1; Revised TSSOP Line Marking table; Added SOIC Land Pattern; Revised Product ID section.

#### Revision C (05/2007)

Removed Preliminary status; Revised Table 1-2, Para. 7 and 8; Revised Table 1-3, CL; Revised trademarks; Replaced Package drawings (Rev. AP); Replaced On-Line Support; Revised Product ID section.

#### **Revision B (12/2003)**

Corrections to Section 1.0, Electrical Characteristics.

#### Revision A (09/2003)

Initial release of this document.

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- Business of Microchip Product selector and ordering guides, latest Microchip press releases, listing of seminars and events, listings of Microchip sales offices, distributors and factory representatives

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- · Technical Support

Customers should contact their distributor, representative or Field Application Engineer (FAE) for support. Local sales offices are also available to help customers. A listing of sales offices and locations is included in the back of this document.

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#### **PRODUCT IDENTIFICATION SYSTEM (NON-AUTOMOTIVE)**

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.		Examples:		
Device	Tape and Reel Temperature Package Range	a) 25AA128T-I/SN: 128 Kbit, 1.8V Serial EEPROM, Industrial Temperature, Tape and Reel, SOIC package		
Device:	<ul> <li>25AA128: 128 Kbit, 1.8V,SPI Serial EEPROM</li> <li>25LC128: 128 Kbit, 2.5V, SPI Serial EEPROM</li> <li>25AA128X: 128 Kbit, 1.8V, SPI Serial EEPROM in alternate pinout (ST only)</li> <li>25LC128X: 128 Kbit, 2.5V, SPI Serial EEPROM in alternate pinout (ST only)</li> </ul>	<ul> <li>b) 25AA128T-I/ST: 128 Kbit, 1.8V Serial EEPROM, Industrial Temperature, Tape and Reel, TSSOP package</li> <li>c) 25LC128-I/P: 128 Kbit, 2.5V Serial EEPROM, Industrial Temperature, PDIP package</li> <li>d) 25LC128T-E/MF: 128 Kbit, 2.5V Serial EEPROM, Extended Temperature, Tape and</li> </ul>		
Tape and Reel Option:	Blank = Standard packaging (tube or tray) T = Tape and Reel <sup>(1)</sup>	Reel, DFN-S package e) 25LC128XT-I/ST: 128 Kbit, 2.5V Serial EEPROM, Industrial Temperature, Tape and		
Temperature Range:	I = $-40^{\circ}$ C to $+85^{\circ}$ C (Industrial) E = $-40^{\circ}$ C to $+125^{\circ}$ C (Extended)	Reel, Alternate pinout, TSSOP package		
Package:	<ul> <li>MF = Plastic Dual Flat, No Lead Package – 5x6x0.85 mm Body, 8-lead (DFN-S)</li> <li>P = Plastic Dual In-Line – 300 mil Body, 8-lead (PDIP)</li> <li>SN = Plastic Small Outline - Narrow, 3.90 mm Body, 8-lead (SOIC)</li> <li>SM = Plastic Small Outline - Medium, 5.28 mm Body, 8-lead (SOIJ)</li> <li>ST = Plastic Thin Shrink Small Outline – 4.4 mm, 8-lead (TSSOP)</li> </ul>	Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering pur- poses and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.		

### **PRODUCT IDENTIFICATION SYSTEM (AUTOMOTIVE)**

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>لاا</u>	<u>-X</u>	<u>/XX</u>	<u>-XXX<sup>(2,3)</sup></u>	Examples		
Device	Tape and Reel	Temperature Range	Package	Variant	a) 25AA128 EEPRO package		
Device:	25AA128: 25LC128:	128 Kbit, 1.8V,S 128 Kbit, 2.5V, \$			<ul> <li>b) 25AA128T-I/ST16KVAO: 128 Kbit, 1.8V Seria EEPROM, Automotive Grade 3, Tape and Ree TSSOP package</li> <li>c) 25LC128-E/SN16KVAO: 128 Kbit, 2.5V Seria EEPROM, Automotive Grade 1, SOIC package</li> </ul>		
Tape and Reel Option:		ndard packaging ( e and Reel <sup>(1)</sup>	tube or tray)		· ·	8T-E/SN16KVAO: 128 Kbit, 2.5V Serial M, Automotive Grade 1, Tape and Reel, ackage	
Temperature Range:		)°C to +85°C (AE ∣°C to +125°C (AE			e) 25LC128-E/ST16KVAO: 128 Kbit, 2.5V Seria EEPROM, Automotive Grade 1, TSSOF package		
Package:	Bo ST = Pla	istic Small Outline dy, 8-lead (SOIC) istic Thin Shrink S ead (TSSOP)	-		ÉEPRO	8T-E/ST16KVAO: 128 Kbit, 2.5V Serial M, Automotive Grade 1, Tape and Reel, package	
Variant <sup>(2,3)</sup> :	16KVAO =	Standard Automo Customer-Specif Process	-		Note 1:	Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.	
					2:	The VAO/VXX automotive variants have been designed, manufactured, tested and qualified in accordance with AEC-Q100 requirements for automotive applications.	
					3:	For customers requesting a PPAP, a customer-specific part number will be generated and provided. A PPAP is not provided for VAO part numbers.	

#### Note the following details of the code protection feature on Microchip devices:

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- Microchip believes that its family of products is secure when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods being used in attempts to breach the code protection features of the Microchip devices. We believe that these methods require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Attempts to breach these code protection features, most likely, cannot be accomplished without violating Microchip's intellectual property rights.
- Microchip is willing to work with any customer who is concerned about the integrity of its code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of its code. Code protection does not
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  other copyrighted work, you may have a right to sue for relief under that Act.

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